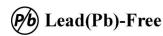
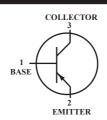


BC807-16/BC807-25 BC807-40

General Purpose Transistor PNP Silicon







Maximum Ratings (TA=25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-45	V
Collector-Base Voltage	VCBO	-50	V
Emitter-Base VOItage	VEBO	-5.0	V
Collector Current-Continuous	IC	500	mAdc

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾ (Note 1.)T _A =25°C Derate above 25°C	PD	225 1.8	mW mW/°C
Thermal Resistance, Junction to Ambient	R _θ JA	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2.) T _A =25°C Derate above 25°C	PD	300 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	R _θ JA	417	°C/W
Junction and Storage, Temperature	T _{J,Tstg}	-55 to +150	°C

Device Marking

BC807-17=5A1, BC807-25=5B1, BC807-40=5C1

 $1.FR-5=1.0 \times 0.75 \times 0.062$ in.

2.Alumina=0.4 x 0.3 x 0.024 in. 99.5% alumina.



Electrical Characteristics (TA=25°C Unless Otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
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Off Characteristics

Collector-Emitter Breakdown Voltage (IC= -10mA)		-45	-	-	V
Collector-Emitter Breakdown Voltage (IC=-10 µA ,VEB=0)		-50	-	-	V
Emitter-Base Breakdown Voltage (I _E =-1.0 μA)	V _{(BR)EBO}	-5.0	-	-	V
Collector Cutoff Current (V _{CB} =20V) (V _{CB} =20V, T _A =150°C)	I _{CBO}	-	-	100 5.0	nA M _A

Electrical Characteristics (TA=25 °C Unless Otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
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On Characteristics

DC Current Gain (I _C = -100mA, V _{CE} =-1.0V) BC807-16 BC807-25 BC807-40	hFE	100 160 250	- - -	250 400 600	-
(I _C = -500mA,V _C E=-1.0V)		40	-	-	
Collector-Emitter Saturation Voltage (IC= -500mA, IB=50mA)	VCE(sat)	-	-	-0.7	V
Base-Emitter On Voltage (IC= ·500mA, IB=·1.0V)	VBE(on)	-	-	-1.2	V

Small-signal Characteristics

Current-Gain-Bandwidth Product (IC= ·10mA, VCE= ·5.0VDC, f=100MHz)	fT	100	-	-	MHz
Output Capacitance (V _{CB} = ·10V, f=1.0MHz)	Cobo	-	10	-	pF



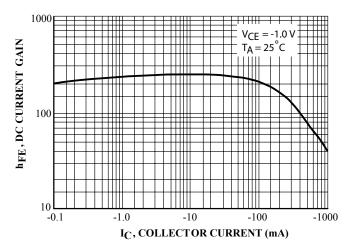


Figure 1. DC Current Gain

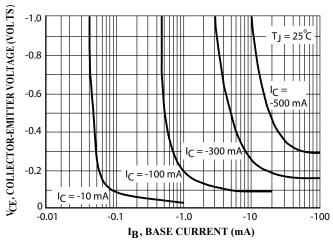


Figure 2. Saturation Region

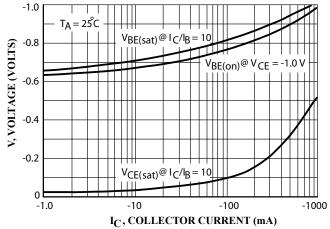


Figure 3. "On" Voltages

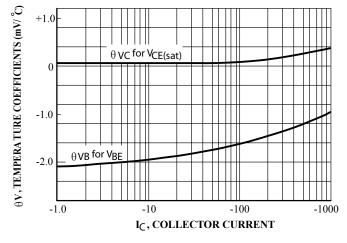


Figure 4. T emperature Coefficients

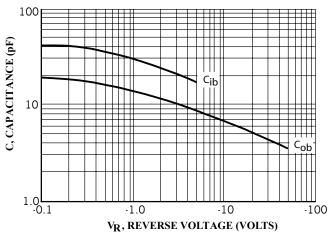
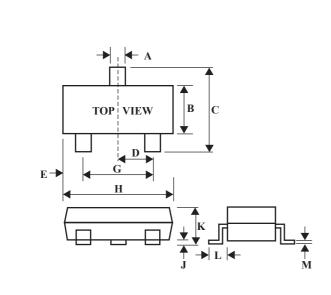


Figure 5. Capacitances



SOT-23 Package Outline Dimension



S OT-23			
Dim	Min	Max	
A	0.35	0.51	
В	1.19	1.40	
C	2.10	3.00	
D	0.85	1.05	
E	0.46	1.00	
G	1.70	2.10	
Н	2.70	3.10	
J	0.01	0.13	
K	0.89	1.10	
L	0.30	0.61	
M	0.076	0.25	